															
FORM PTC IREV. 7.80	1		PATE	NT AN		Attorney Dock 15.52/6357	ket No.	Serial No. 10/025,347							
INFORMATION DISCLOSURE STATEMENT Co. Applicant: HOGYOKU															
(Use several sheets if necessary) APR 1 5 2002											Filing Date 12/19/01	•	Group 2922		
LIS PATENT DOCUMENTS															
U.S. PATEINT DOCUMENTS															
Examiner Iņitial		Document Number						ate	Name		Class	Sub- Filing Date Appropriate			
							\triangle								
			\												
															\angle
														Ų	7
)	· · · · · · · · · · · · · · · · · · ·		•	·	<u> </u>									
FOREIGN PATENT DOCUMENTS															
		Document Number						Date		Со	untry	Class	Sub- Class	Translation	
													Class	Yes	No
		•				$\overline{}$	$\overline{}$							1	
	1			1							1				
\					1										
. /						1									,
								1			\mathcal{I}				
OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)															
	Wei and Antoniadis, "Minimizing Floating-Body-Induced Threshold Voltage Variation in Partialy Depleted SOI CMOS," IEEE Electron Device Letters, Vol. 17, No. 8 (August 1996) at pp. 391-394.														
No.	_									/	$\overline{}$			$\overline{}$	
				\				<u></u>					TEC	$\overline{}$	
	_	$\frac{1}{\sqrt{1}}$					Τ			$\stackrel{\sim}{\sim}$					_
Examiner	ļ	HO	, /	براراد	B)	//	Dat	e Consi	dered	C	1/22/	0) INOLOGY	APR I	RFO
* EXAMINER:	Initi	al if referen	ce consid	ered, wh	ether or	not citation	is in cor	nformance	with MPER	P 609; D	raw line through cit	ation if not in a		not consid	Tij
Include copy of	f thi	s form with	next com	municati	on to app	plicant.					raw line through cite	*	<u> </u>	2002	}
												Atalas Thomas	R 2800	ر	ر
												i	0		